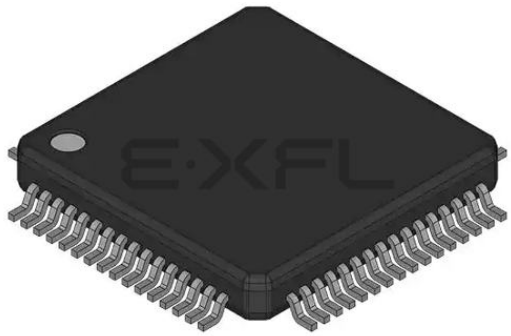

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I²C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	45
Program Memory Size	384KB (384K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	28K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=spc5603bf2vlh4

Table 1. MPC5604B/C device comparison[1] (continued)

Feature	Device															
	MPC5602BxLH	MPC5602BxLL	MPC5602BxLQ	MPC5602CxLH	MPC5602CxLL	MPC5603BxLH	MPC5603BxLL	MPC5603BxLQ	MPC5603CxLH	MPC5603CxLL	MPC5604BxLH	MPC5604BxLL	MPC5604BxLQ	MPC5604CxLH	MPC5604CxLL	MPC5604BxMG
• PWM + IC/OC[4]	10 ch	20 ch	40 ch	10 ch	20 ch	10 ch	20 ch	40 ch	10 ch	20 ch	10 ch	20 ch	40 ch	10 ch	20 ch	40 ch
• IC/OC[4]	—	3 ch	6 ch	—	3 ch	—	3 ch	6 ch	—	3 ch	—	3 ch	6 ch	—	3 ch	6 ch
SCI (LINFlex)	3[5]			4												
SPI (DSPI)	2	3		2	3	2	3		2	3	2	3		2	3	
CAN (FlexCAN)	2[6]			5	6	3[7]			5	6	3[7]			5	6	
I^2C	1															
32 kHz oscillator	Yes															
GPIO[8]	45	79	123	45	79	45	79	123	45	79	45	79	123	45	79	123
Debug	JTAG															Nexus2+
Package	64 LQFP	100 LQFP	144 LQFP	64 LQFP	100 LQFP	64 LQFP	100 LQFP	144 LQFP	64 LQFP	100 LQFP	64 LQFP	100 LQFP	144 LQFP	64 LQFP	100 LQFP	208 MAPBGA[9]

1 Feature set dependent on selected peripheral multiplexing—table shows example implementation.

2 Based on 125 °C ambient operating temperature.

3 See the eMIOS section of the device reference manual for information on the channel configuration and functions.

4 IC – Input Capture; OC – Output Compare; PWM – Pulse Width Modulation; MC – Modulus counter.

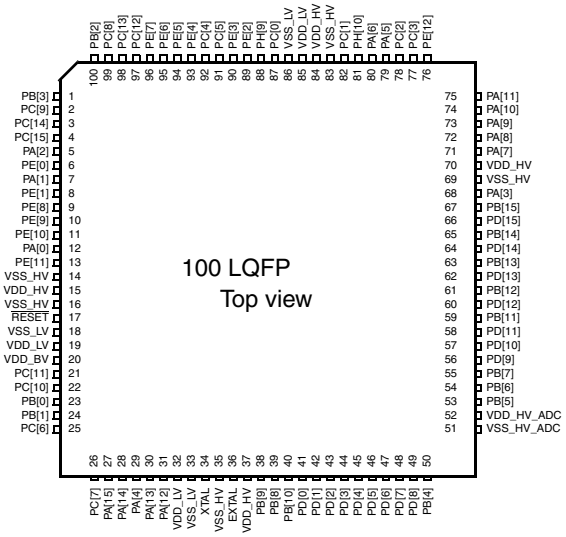
5 SCI0, SCI1 and SCI2 are available. SCI3 is not available.

6 CAN0, CAN1 are available. CAN2, CAN3, CAN4 and CAN5 are not available.

7 CAN0, CAN3 and either CAN1 or CAN4 are available. CAN2, CAN5 and CAN6 are not available

8 I/O count based on multiplexing with peripherals.

9 208 MAPBGA available only as development package for Nexus2+.



Note:
Availability of port pin alternate functions depends on product selection.

Figure 4. LQFP 100-pin configuration

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PC[15]	PCR[47]	AF0 AF1 AF2 AF3	GPIO[47] E0UC[15] CS0_2 —	SIUL eMIOS_0 DSPI_2 —	I/O I/O I/O —	M	Tristate	—	—	4	4	D3
PD[0]	PCR[48]	AF0 AF1 AF2 AF3 —	GPIO[48] — — — GPI[4]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	41	63	P12
PD[1]	PCR[49]	AF0 AF1 AF2 AF3 —	GPIO[49] — — — GPI[5]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	42	64	T12
PD[2]	PCR[50]	AF0 AF1 AF2 AF3 —	GPIO[50] — — — GPI[6]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	43	65	R12
PD[3]	PCR[51]	AF0 AF1 AF2 AF3 —	GPIO[51] — — — GPI[7]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	44	66	P13
PD[4]	PCR[52]	AF0 AF1 AF2 AF3 —	GPIO[52] — — — GPI[8]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	45	67	R13
PD[5]	PCR[53]	AF0 AF1 AF2 AF3 —	GPIO[53] — — — GPI[9]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	46	68	T13
PD[6]	PCR[54]	AF0 AF1 AF2 AF3 —	GPIO[54] — — — GPI[10]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	47	69	T14

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PD[15]	PCR[63]	AF0 AF1 AF2 AF3 —	GPIO[63] CS2_1 E0UC[27] — ANS[7]	SIUL DSPI_1 eMIOS_0 — ADC	I/O O I/O — I	J	Tristate	—	—	66	88	L14
PE[0]	PCR[64]	AF0 AF1 AF2 AF3 — —	GPIO[64] E0UC[16] — — CAN5RX[11] WKPU[6][4]	SIUL eMIOS_0 — — FlexCAN_5 WKPU	I/O I/O — — I I	S	Tristate	—	—	6	10	F1
PE[1]	PCR[65]	AF0 AF1 AF2 AF3	GPIO[65] E0UC[17] CAN5TX[11] —	SIUL eMIOS_0 FlexCAN_5 —	I/O I/O O —	M	Tristate	—	—	8	12	F4
PE[2]	PCR[66]	AF0 AF1 AF2 AF3 —	GPIO[66] E0UC[18] — — SIN_1	SIUL eMIOS_0 — — DSPI_1	I/O I/O — — I	M	Tristate	—	—	89	128	D7
PE[3]	PCR[67]	AF0 AF1 AF2 AF3	GPIO[67] E0UC[19] SOUT_1 —	SIUL eMIOS_0 DSPI_1 —	I/O I/O O —	M	Tristate	—	—	90	129	C7
PE[4]	PCR[68]	AF0 AF1 AF2 AF3 —	GPIO[68] E0UC[20] SCK_1 — EIRQ[9]	SIUL eMIOS_0 DSPI_1 — SIUL	I/O I/O I/O — I	M	Tristate	—	—	93	132	D6
PE[5]	PCR[69]	AF0 AF1 AF2 AF3	GPIO[69] E0UC[21] CS0_1 MA[2]	SIUL eMIOS_0 DSPI_1 ADC	I/O I/O I/O O	M	Tristate	—	—	94	133	C6
PE[6]	PCR[70]	AF0 AF1 AF2 AF3	GPIO[70] E0UC[22] CS3_0 MA[1]	SIUL eMIOS_0 DSPI_0 ADC	I/O I/O O O	M	Tristate	—	—	95	139	B5
PE[7]	PCR[71]	AF0 AF1 AF2 AF3	GPIO[71] E0UC[23] CS2_0 MA[0]	SIUL eMIOS_0 DSPI_0 ADC	I/O I/O O O	M	Tristate	—	—	96	140	C4

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PE[8]	PCR[72]	AF0 AF1 AF2 AF3	GPIO[72] CAN2TX[12] E0UC[22] CAN3TX[11]	SIUL FlexCAN_2 eMIOS_0 FlexCAN_3	I/O O I/O O	M	Tristate	—	—	9	13	G2
PE[9]	PCR[73]	AF0 AF1 AF2 AF3 — — —	GPIO[73] — E0UC[23] — WKPU[7][4] CAN2RX[12] CAN3RX[11]	SIUL — eMIOS_0 — WKPU FlexCAN_2 FlexCAN_3	I/O — I/O — I I I	S	Tristate	—	—	10	14	G1
PE[10]	PCR[74]	AF0 AF1 AF2 AF3 —	GPIO[74] LIN3TX CS3_1 — EIRQ[10]	SIUL LINFlex_3 DSPI_1 — SIUL	I/O O O — I	S	Tristate	—	—	11	15	G3
PE[11]	PCR[75]	AF0 AF1 AF2 AF3 — —	GPIO[75] — CS4_1 — LIN3RX WKPU[14][4]	SIUL — DSPI_1 — LINFlex_3 WKPU	I/O — O — I I	S	Tristate	—	—	13	17	H2
PE[12]	PCR[76]	AF0 AF1 AF2 AF3 — —	GPIO[76] — E1UC[19][13] — SIN_2 EIRQ[11]	SIUL — eMIOS_1 — DSPI_2 SIUL	I/O — I/O — I I	S	Tristate	—	—	76	109	C14
PE[13]	PCR[77]	AF0 AF1 AF2 AF3	GPIO[77] SOUT2 E1UC[20] —	SIUL DSPI_2 eMIOS_1 —	I/O O I/O —	S	Tristate	—	—	—	103	D15
PE[14]	PCR[78]	AF0 AF1 AF2 AF3 —	GPIO[78] SCK_2 E1UC[21] — EIRQ[12]	SIUL DSPI_2 eMIOS_1 — SIUL	I/O I/O I/O — I	S	Tristate	—	—	—	112	C13
PE[15]	PCR[79]	AF0 AF1 AF2 AF3	GPIO[79] CS0_2 E1UC[22] —	SIUL DSPI_2 eMIOS_1 —	I/O I/O I/O —	M	Tristate	—	—	—	113	A13

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PF[0]	PCR[80]	AF0 AF1 AF2 AF3 —	GPIO[80] E0UC[10] CS3_1 — ANS[8]	SIUL eMIOS_0 DSPI_1 — ADC	I/O I/O O — I	J	Tristate	—	—	—	55	N10
PF[1]	PCR[81]	AF0 AF1 AF2 AF3 —	GPIO[81] E0UC[11] CS4_1 — ANS[9]	SIUL eMIOS_0 DSPI_1 — I	I/O I/O O — I	J	Tristate	—	—	—	56	P10
PF[2]	PCR[82]	AF0 AF1 AF2 AF3 —	GPIO[82] E0UC[12] CS0_2 — ANS[10]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O I/O — I	J	Tristate	—	—	—	57	T10
PF[3]	PCR[83]	AF0 AF1 AF2 AF3 —	GPIO[83] E0UC[13] CS1_2 — ANS[11]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	58	R10
PF[4]	PCR[84]	AF0 AF1 AF2 AF3 —	GPIO[84] E0UC[14] CS2_2 — ANS[12]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	59	N11
PF[5]	PCR[85]	AF0 AF1 AF2 AF3 —	GPIO[85] E0UC[22] CS3_2 — ANS[13]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	60	P11
PF[6]	PCR[86]	AF0 AF1 AF2 AF3 —	GPIO[86] E0UC[23] — — ANS[14]	SIUL eMIOS_0 — — ADC	I/O I/O — — I	J	Tristate	—	—	—	61	T11
PF[7]	PCR[87]	AF0 AF1 AF2 AF3 —	GPIO[87] — — — ANS[15]	SIUL — — — ADC	I/O — — — I	J	Tristate	—	—	—	62	R11

Table 17. SLOW configuration output buffer electrical characteristics

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
V_{OH}	CC	P	Output high level SLOW configuration	Push Pull	I_{OH} = –2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	$0.8V_{DD}$	—	—	V
		C			I_{OH} = –2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 1[2]	$0.8V_{DD}$	—	—	
		C			I_{OH} = –1 mA, V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V_{DD}–0.8	—	—	
V_{OL}	CC	P	Output low level SLOW configuration	Push Pull	I_{OL} = 2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	—	—	$0.1V_{DD}$	V
		C			I_{OL} = 2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 1[2]	—	—	$0.1V_{DD}$	
		C			I_{OL} = 1 mA, V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	—	—	0.5	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

2 The configuration PAD3V5 = 1 when V_{DD} = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus output (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

Table 18. MEDIUM configuration output buffer electrical characteristics

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
V_{OH}	CC	C	Output high level MEDIUM configuration	Push Pull	I_{OH} = –3.8 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	$0.8V_{DD}$	—	—	V
		P			I_{OH} = –2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	$0.8V_{DD}$	—	—	
		C			I_{OH} = –1 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 1[2]	$0.8V_{DD}$	—	—	
		C			I_{OH} = –1 mA, V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V_{DD}–0.8	—	—	
		C			I_{OH} = –100 µA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	$0.8V_{DD}$	—	—	

2.15.4 Output pin transition times

Table 20. Output pin transition times

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
t_{tr}	CC	D	Output transition time output pin[2] SLOW configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	50	ns
		T		C_L = 50 pF		—	—	100	
		D		C_L = 100 pF		—	—	125	
		D		C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	50	
		T		C_L = 50 pF		—	—	100	
		D		C_L = 100 pF		—	—	125	
t_{tr}	CC	D	Output transition time output pin[2] MEDIUM configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	10	ns
		T		C_L = 50 pF		—	—	20	
		D		C_L = 100 pF		—	—	40	
		D		C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	12	
		T		C_L = 50 pF		—	—	25	
		D		C_L = 100 pF		—	—	40	
t_{tr}	CC	D	Output transition time output pin[2] FAST configuration	C_L = 25 pF	V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	4	ns
				C_L = 50 pF		—	—	6	
				C_L = 100 pF		—	—	12	
				C_L = 25 pF	V_{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	4	
				C_L = 50 pF		—	—	7	
				C_L = 100 pF		—	—	12	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

2 C_L includes device and package capacitances (C_{PKG} < 5 pF).

2.15.5 I/O pad current specification

The I/O pads are distributed across the I/O supply segment. Each I/O supply segment is associated to a V_{DD}/V_{SS} supply pair as described in Table 21.

Table 21. I/O supply segment

Package	Supply segment					
	1	2	3	4	5	6
208 MAPBGA[1]	Equivalent to 144 LQFP segment pad distribution				MCKO	MDOn/MSEO
144 LQFP	pin20–pin49	pin51–pin99	pin100–pin122	pin 123–pin19	—	—
100 LQFP	pin16–pin35	pin37–pin69	pin70–pin83	pin 84–pin15	—	—
64 LQFP	pin8–pin26	pin28–pin55	pin56–pin7	—	—	—

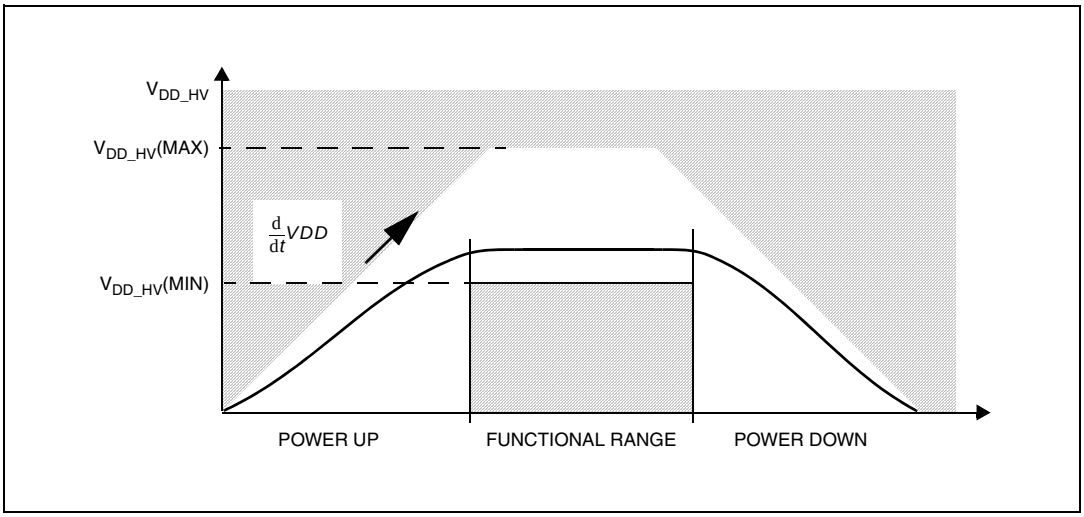


Figure 11. V_{DD_HV} and V_{DD_BV} maximum slope

When STANDBY mode is used, further constraints are applied to the both V_{DD_HV} and V_{DD_BV} in order to guarantee correct regulator function during STANDBY exit. This is described on Figure 12.

STANDBY regulator constraints should normally be guaranteed by implementing equivalent of CSTDBY capacitance on application board (capacitance and ESR typical values), but would actually depend on exact characteristics of application external regulator.

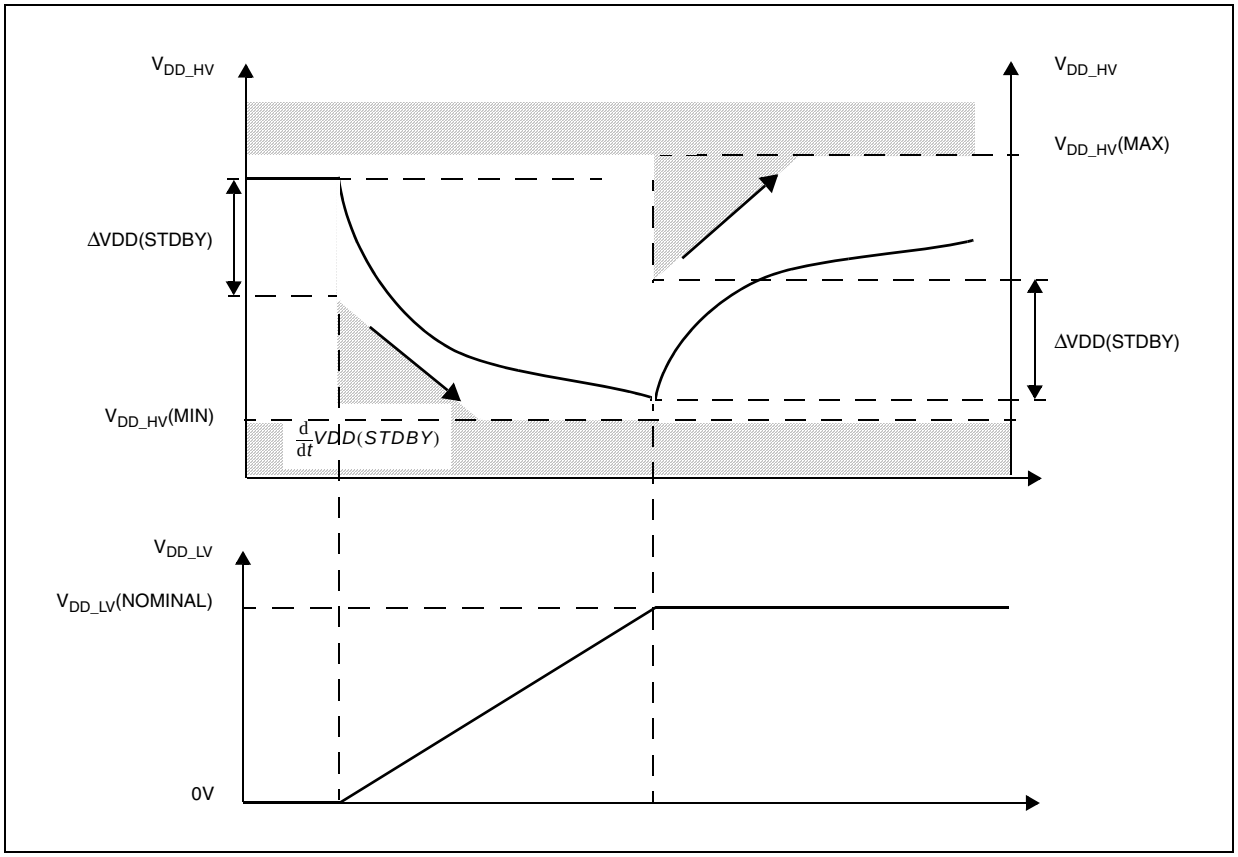


Figure 12. V_{DD_HV} and V_{DD_BV} supply constraints during STANDBY mode exit

2.18 Power consumption

Table 27 provides DC electrical characteristics for significant application modes. These values are indicative values; actual consumption depends on the application.

Table 27. Power consumption on VDD_BV and VDD_HV

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
I_{DDMAX}[2]	CC	D	RUN mode maximum average current	—		—	115	140[3]	mA
I_{DDRUN}[4]	CC	T	RUN mode typical average current[5]	f_{CPU} = 8 MHz		—	7	—	mA
		T		f_{CPU} = 16 MHz		—	18	—	
		T		f_{CPU} = 32 MHz		—	29	—	
		P		f_{CPU} = 48 MHz		—	40	100	
		P		f_{CPU} = 64 MHz		—	51	125	
I_{DDHALT}	CC	C	HALT mode current[6]	Slow internal RC oscillator (128 kHz) running	T_A = 25 °C	—	8	15	mA
		P			T_A = 125 °C	—	14	25	
I_{DDSTOP}	CC	P	STOP mode current[7]	Slow internal RC oscillator (128 kHz) running	T_A = 25 °C	—	180	700[8]	µA
		D			T_A = 55 °C	—	500	—	
		D			T_A = 85 °C	—	1	6[8]	mA
		D			T_A = 105 °C	—	2	9[8]	
		P			T_A = 125 °C	—	4.5	12[8]	
$I_{DDSTDBY2}$	CC	P	STANDBY2 mode current[9]	Slow internal RC oscillator (128 kHz) running	T_A = 25 °C	—	30	100	µA
		D			T_A = 55 °C	—	75	—	
		D			T_A = 85 °C	—	180	700	
		D			T_A = 105 °C	—	315	1000	
		P			T_A = 125 °C	—	560	1700	
$I_{DDSTDBY1}$	CC	T	STANDBY1 mode current[10]	Slow internal RC oscillator (128 kHz) running	T_A = 25 °C	—	20	60	µA
		D			T_A = 55 °C	—	45	—	
		D			T_A = 85 °C	—	100	350	
		D			T_A = 105 °C	—	165	500	
		D			T_A = 125 °C	—	280	900	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

2 I_{DDMAX} is drawn only from the V_{DD_BV} pin. Running consumption does not include I/Os toggling which is highly dependent on the application. The given value is thought to be a worst case value with all peripherals running, and code fetched from code flash while modify operation ongoing on data flash. Notice that this value can be significantly reduced by application: switch off not used peripherals (default), reduce peripheral frequency through internal prescaler, fetch from RAM most used functions, use low power mode when possible.

3 Higher current may be sinked by device during power-up and standby exit. Please refer to in rush current on Table 25.

4 I_{DDRUN} is drawn only from the V_{DD_BV} pin. RUN current measured with typical application with accesses on both flash and RAM.

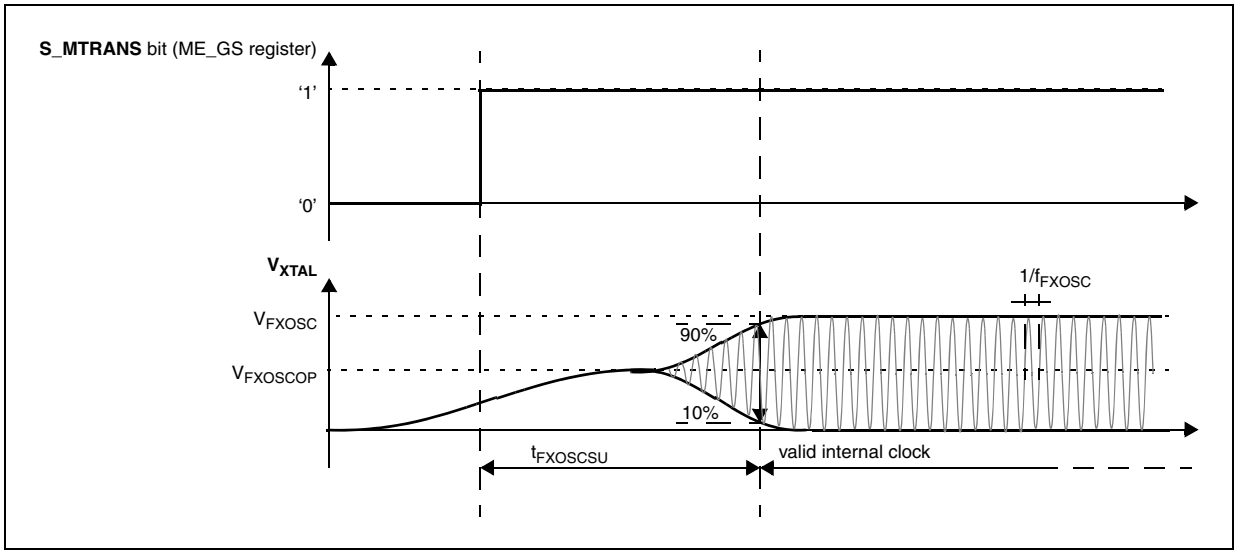


Figure 15. Fast external crystal oscillator (4 to 16 MHz) timing diagram

2 This is the recommended range of load capacitance at OSC32K_XTAL and OSC32K_EXTAL with respect to ground. It includes all the parasitics due to board traces, crystal and package.

3 Maximum ESR (R_m) of the crystal is 50 kΩ

4 C0 includes a parasitic capacitance of 2.0 pF between OSC32K_XTAL and OSC32K_EXTAL pins

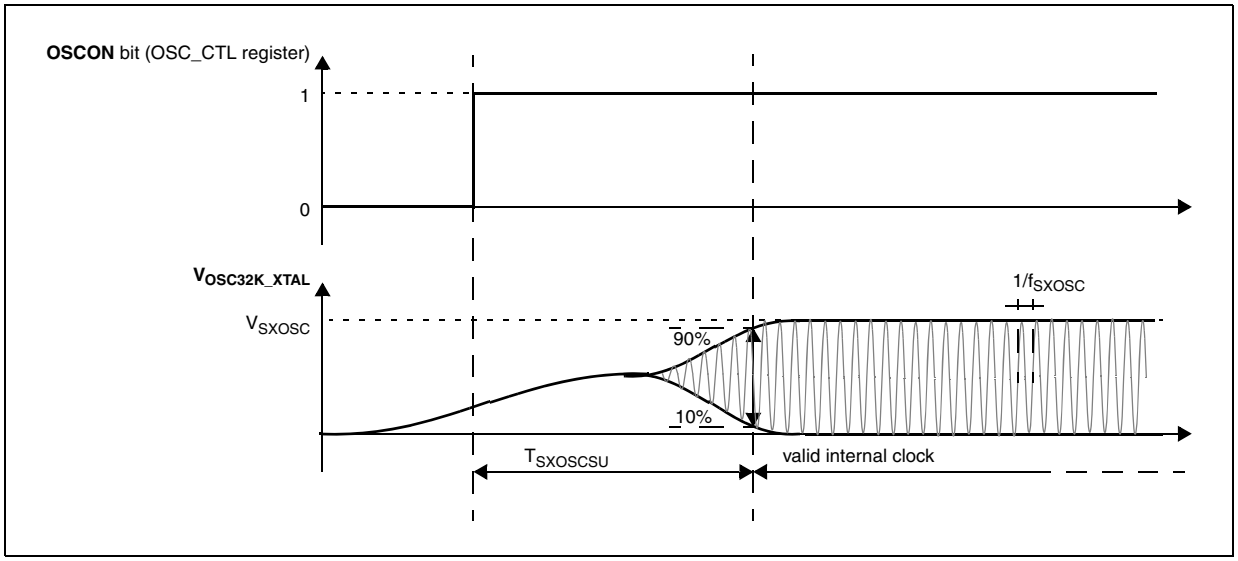


Figure 18. Slow external crystal oscillator (32 kHz) timing diagram

Table 39. Slow external crystal oscillator (32 kHz) electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
f_{SXOSC}	SR	—	Slow external crystal oscillator frequency	—	32	32.768	40	kHz
V_{SXOSC}	CC	T	Oscillation amplitude	—	—	2.1	—	V
$I_{SXOSCBIAS}$	CC	T	Oscillation bias current	—	—	2.5	—	µA
I_{SXOSC}	CC	T	Slow external crystal oscillator consumption	—	—	—	8	µA
$T_{SXOSCSU}$	CC	T	Slow external crystal oscillator start-up time	—	—	—	2^2	s

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified. Values are specified for no neighbor GPIO pin activity. If oscillator is enabled (OSC32K_XTAL and OSC32K_EXTAL pins), neighboring pins should not toggle.

2 Start-up time has been measured with EPSON TOYOCOM MC306 crystal. Variation may be seen with other crystal.

2.23 FMPLL electrical characteristics

The device provides a frequency-modulated phase-locked loop (FMPLL) module to generate a fast system clock from the main oscillator driver.

2.26 ADC electrical characteristics

2.26.1 Introduction

The device provides a 10-bit Successive Approximation Register (SAR) analog-to-digital converter.

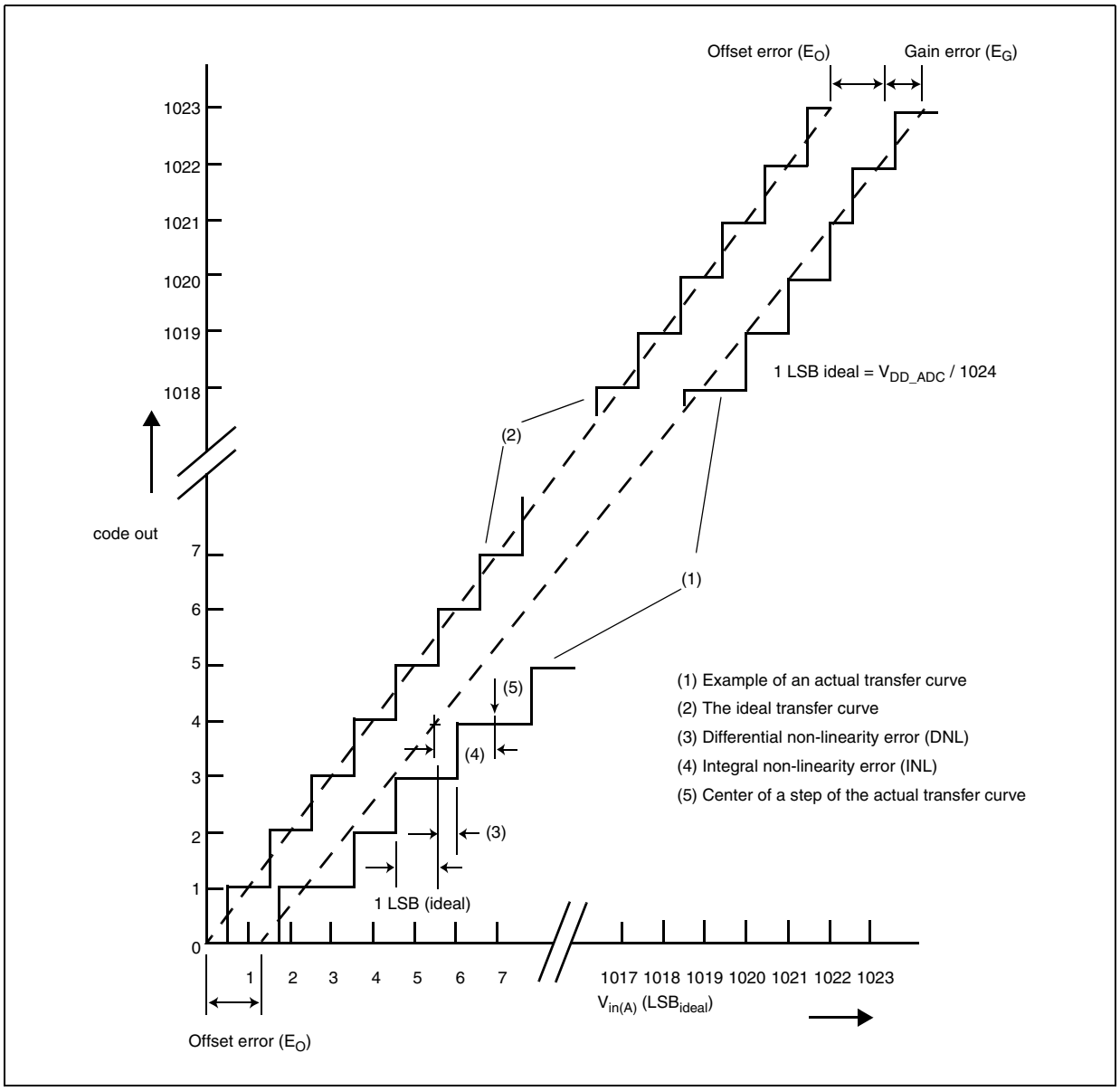


Figure 19. ADC characteristic and error definitions

2.26.2 Input impedance and ADC accuracy

In the following analysis, the input circuit corresponding to the precise channels is considered.

To preserve the accuracy of the A/D converter, it is necessary that analog input pins have low AC impedance. Placing a capacitor with good high frequency characteristics at the input pin of the device can

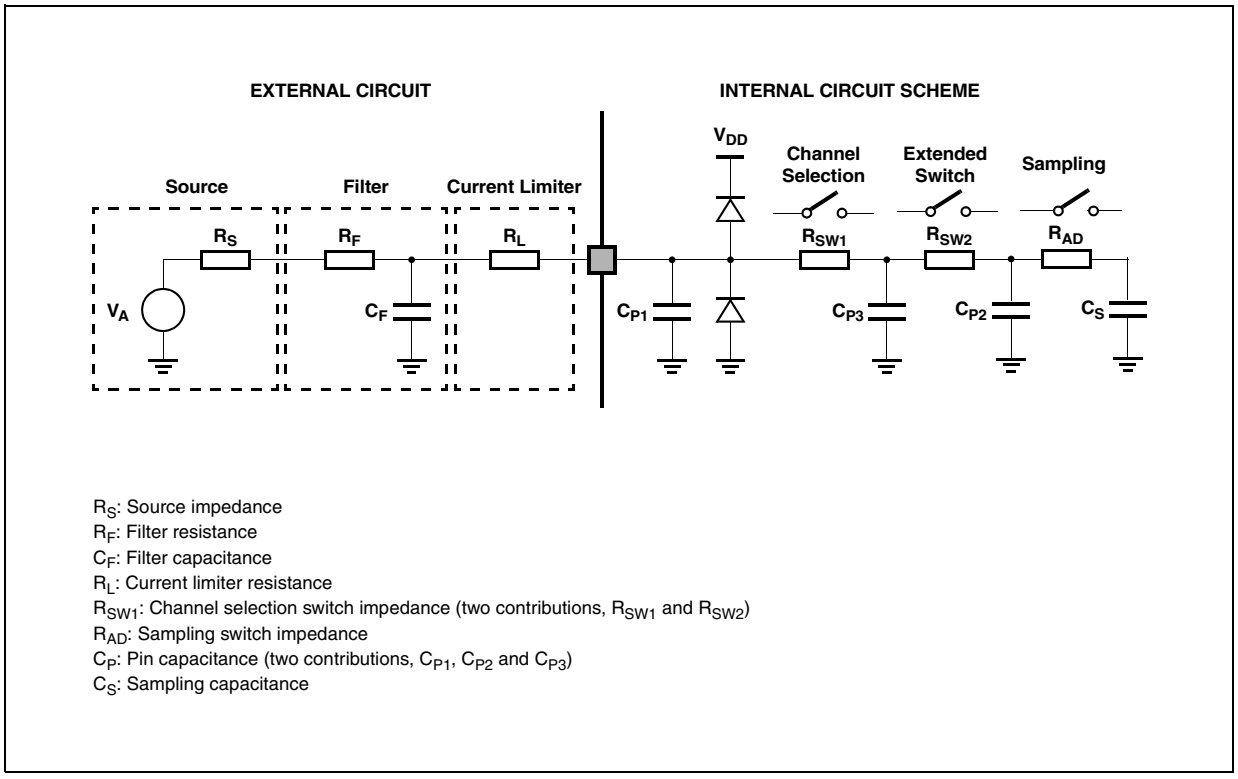


Figure 21. Input equivalent circuit (extended channels)

A second aspect involving the capacitance network shall be considered. Assuming the three capacitances C_F, C_{P1} and C_{P2} are initially charged at the source voltage V_A (refer to the equivalent circuit in Figure 20): A charge sharing phenomenon is installed when the sampling phase is started (A/D switch close).

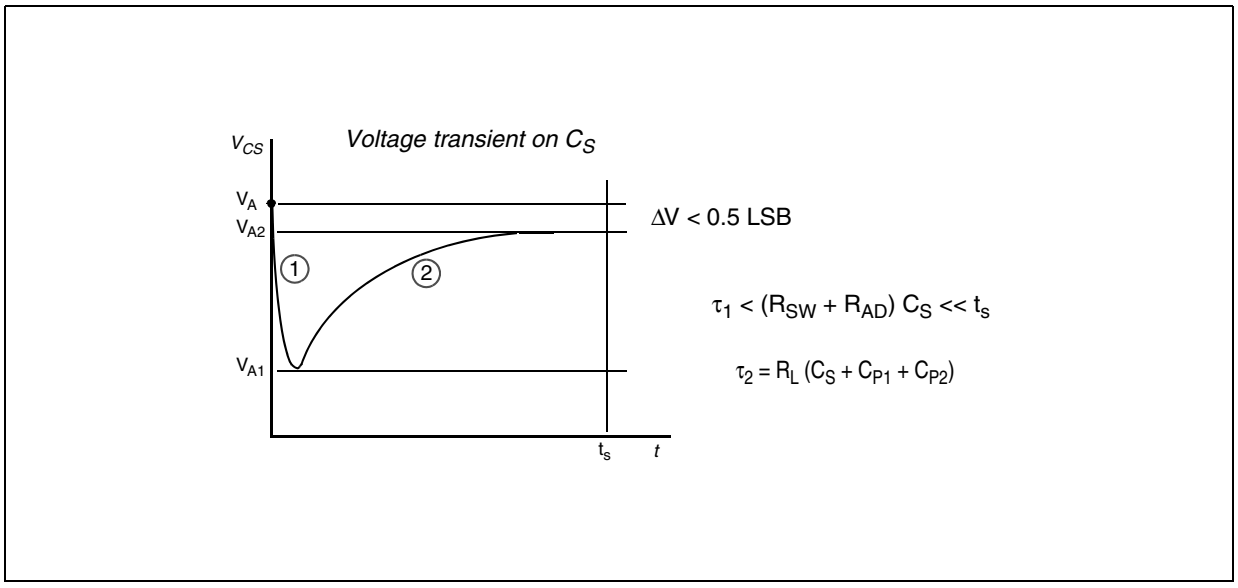


Figure 22. Transient behavior during sampling phase

In particular two different transient periods can be distinguished:

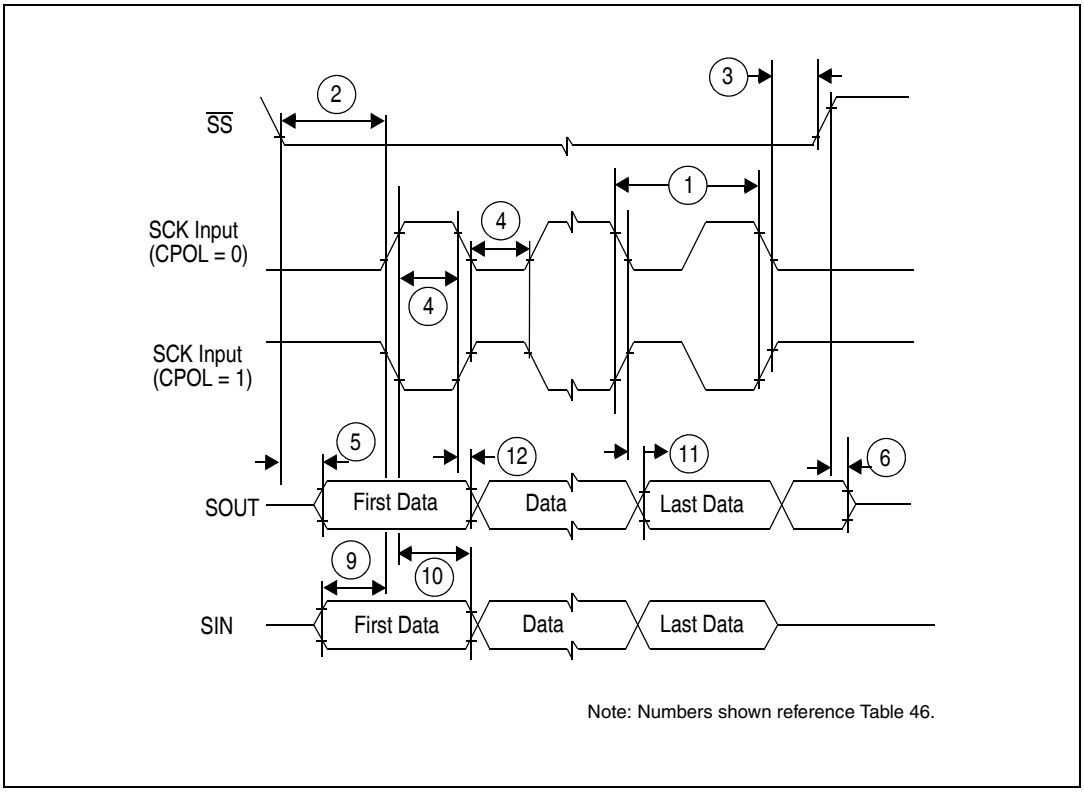


Figure 26. DSPI classic SPI timing – slave, CPHA = 0

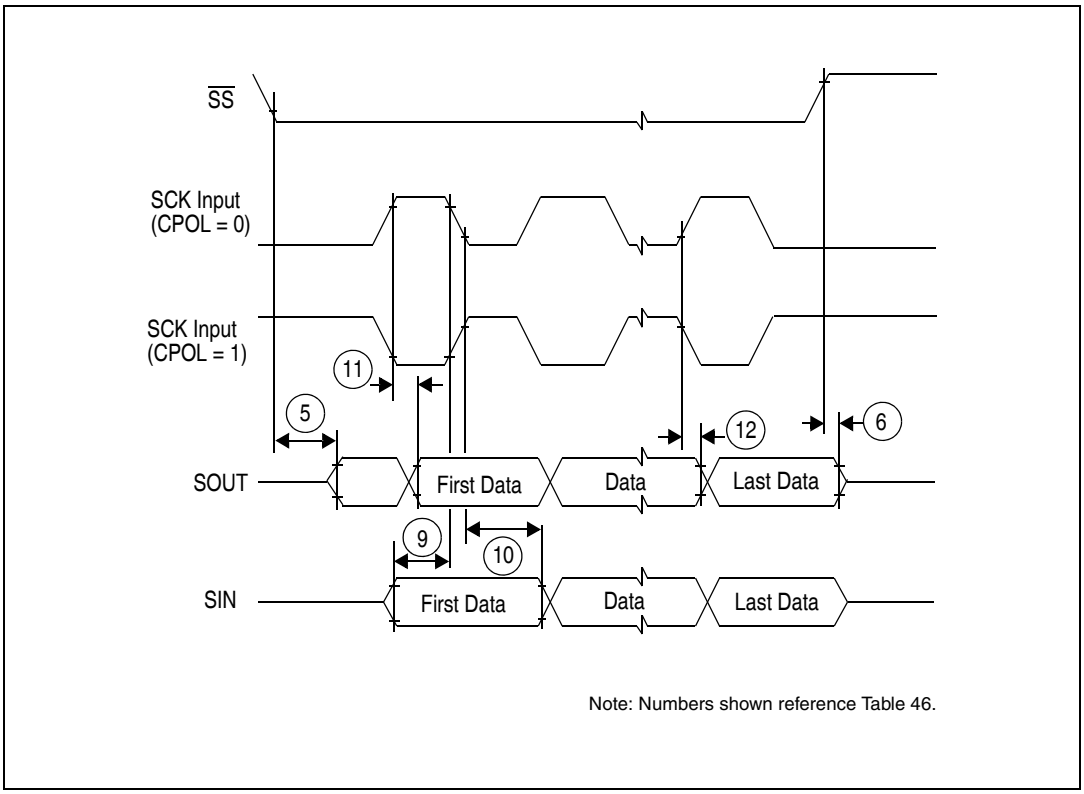


Figure 27. DSPI classic SPI timing – slave, CPHA = 1

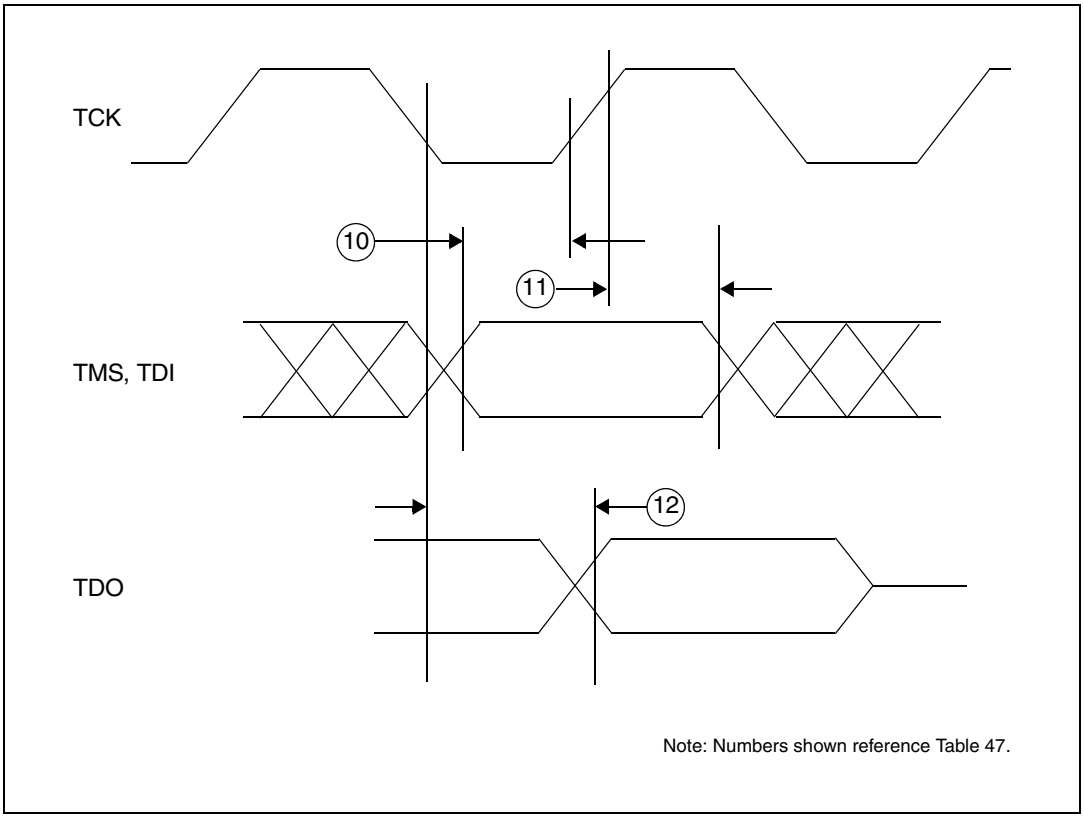


Figure 33. Nexus TDI, TMS, TDO timing

2.27.4 JTAG characteristics

Table 48. JTAG characteristics

No.	Symbol		C	Parameter	Value			Unit
					Min	Typ	Max	
1	t_{JCYC}	CC	D	TCK cycle time	64	—	—	ns
2	t_{TDIS}	CC	D	TDI setup time	15	—	—	ns
3	t_{TDIH}	CC	D	TDI hold time	5	—	—	ns
4	t_{TMSS}	CC	D	TMS setup time	15	—	—	ns
5	t_{TMSH}	CC	D	TMS hold time	5	—	—	ns
6	t_{TDOV}	CC	D	TCK low to TDO valid	—	—	33	ns
7	t_{TDOI}	CC	D	TCK low to TDO invalid	6	—	—	ns

3.1.1 64 LQFP

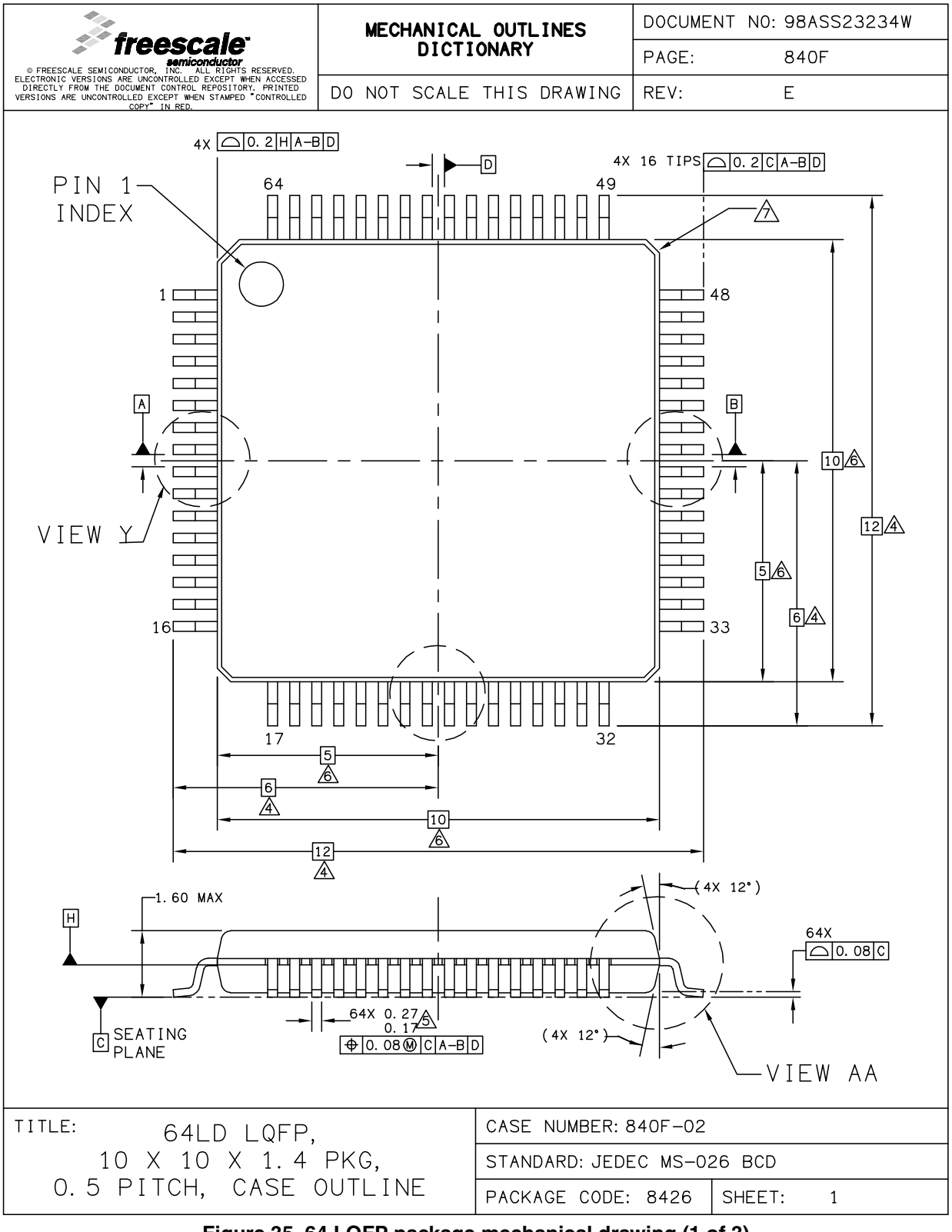


Figure 35. 64 LQFP package mechanical drawing (1 of 3)

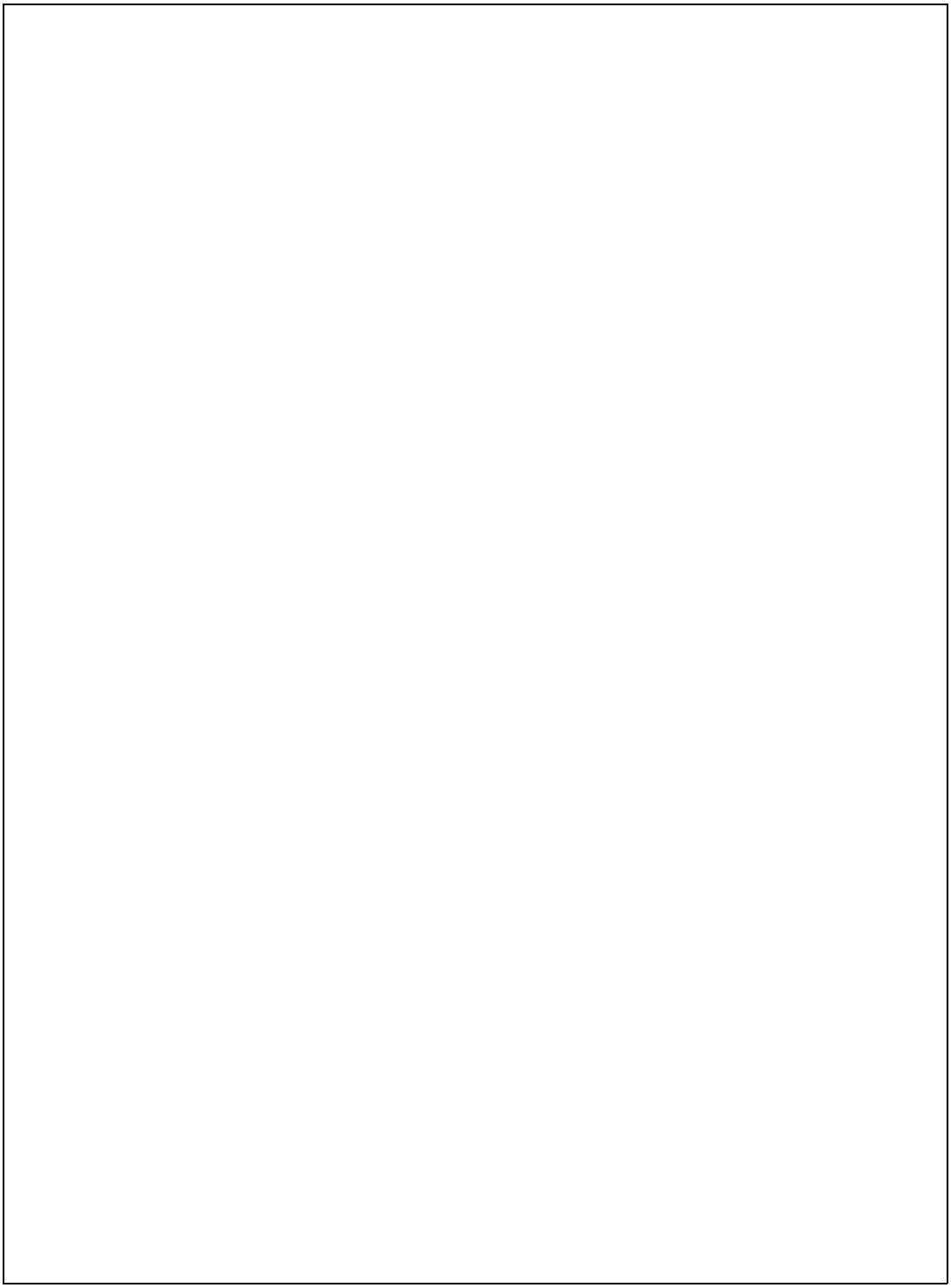


Figure 42. 144 LQFP package mechanical drawing (2 of 2)

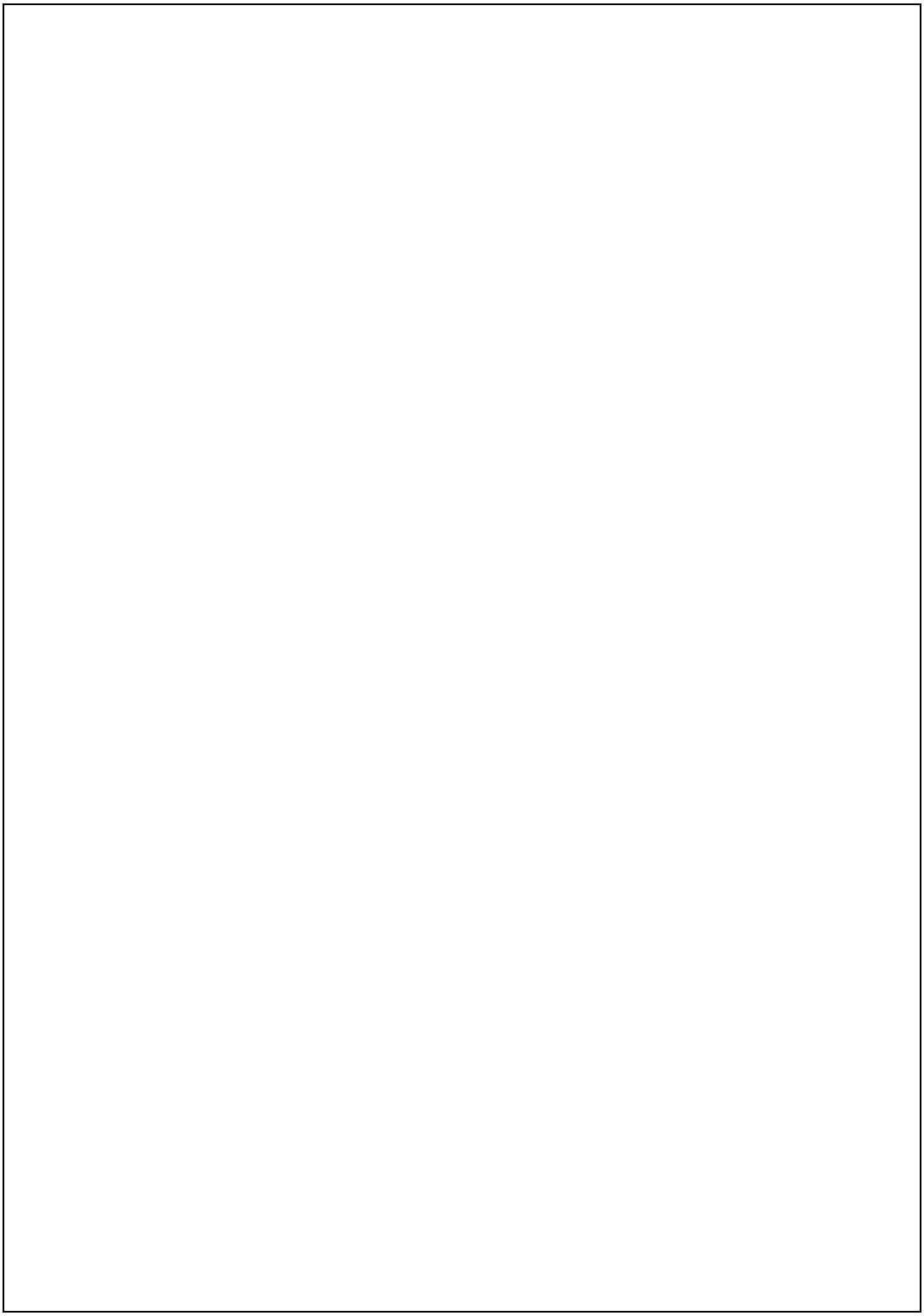


Figure 44. 208 MAPBGA package mechanical drawing (2 of 2)

Table 49. Revision history (continued)

Revision	Date	Description of Changes
10	15 Oct 2012	Table 2 (Bolero 512K device comparison), added footnote for MPC5603BxLH and MPC5604BxLH about FlexCAN availability. Table 2 (MPC5604B/C series block summary), replaced “System watchdog timer” with “Software watchdog timer” and specified AUTOSAR (Automotive Open System Architecture) Table 5 (Functional port pin descriptions): replaced footnote “Available only on MPC560xC versions and MPC5604B 208 MAPBGA devices” with “Available only on MPC560xC versions, MPC5603B 64 LQFP, MPC5604B 64 LQFP and MPC5604B 208 MAPBGA devices”, replaced VDD with VDD_HV Figure 10 (Voltage regulator capacitance connection), updated pin name appearance Renamed Figure 11 (V_{DD_HV} and V_{DD_BV} maximum slope) (was “VDD and VDD_BV maximum slope”) Renamed Figure 12 (V_{DD_HV} and V_{DD_BV} supply constraints during STANDBY mode exit) (was “VDD and VDD_BV supply constraints during STANDBY mode exit”) Table 12 (Recommended operating conditions (3.3 V)), added minimum value of T_{VDD} and footnote about it. Table 13 (Recommended operating conditions (5.0 V)), added minimum value of T_{VDD} and footnote about it. Section 2.17.1, “Voltage regulator electrical characteristics: replaced “slew rate of V_{DD}/V_{DD_BV}” with “slew rate of both V_{DD_HV} and V_{DD_BV}” replaced “When STANDBY mode is used, further constraints apply to the V_{DD}/V_{DD_BV} in order to guarantee correct regulator functionality during STANDBY exit.” with “When STANDBY mode is used, further constraints are applied to the both V_{DD_HV} and V_{DD_BV} in order to guarantee correct regulator function during STANDBY exit.” Table 27 (Power consumption on VDD_BV and VDD_HV), updated footnotes of I_{DDMAX} and I_{DDRUN} stating that both currents are drawn only from the V_{DD_BV} pin. Table 31 (Flash memory power supply DC electrical characteristics), in the parameter column replaced V_{DD_BV} and V_{DD_HV} respectively with VDD_BV and VDD_HV. Table 45 (On-chip peripherals current consumption), in the parameter column replaced V_{DD_BV}, V_{DD_HV} and $V_{DD\_HV\_ADC}$ respectively with VDD_BV, VDD_HV and VDD_HV_ADC Updated Section 2.26.2, “Input impedance and ADC accuracy Table 46 (DSPI characteristics), modified symbol for t_{PCSC} and t_{PASC}
11	14 Nov 2012	In the cover feature list: added “and ECC” at the end of “Up to 512 KB on-chip code flash supported with the flash controller” added “with ECC” at the end of “Up to 48 KB on-chip SRAM” Table 12 (Recommended operating conditions (3.3 V)), removed minimum value of T_{VDD} and relative footnote. Table 13 (Recommended operating conditions (5.0 V)), removed minimum value of T_{VDD} and relative footnote.
12	19 Mar 2014	Added “K=TSMC Fab” against the Fab and mask indicator in Figure 45 (Commercial product code structure).